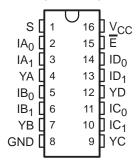
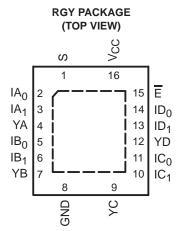
- Wide Bandwidth (BW = 350 MHz Min)
- Low Differential Crosstalk (X_{TALK} = -68 dB Typ)
- Low Power Consumption (I_{CC} = 3 μA Max)
- Bidirectional Data Flow, With Near-Zero Propagation Delay
- Low ON-State Resistance (r_{on} = 5 Ω Typ)
- Rail-to-Rail Switching on Data I/O Ports (0 to V_{CC})
- V_{CC} Operating Range From 3 V to 3.6 V
- I_{off} Supports Partial-Power-Down Mode Operation

- Data and Control Inputs Have Undershoot Clamp Diodes
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)
- Suitable for Both 10 Base-T/100 Base-T Signaling







description/ordering information

The TI TS3L100 LAN switch is a 4-bit 1-of-2 multiplexer/demultiplexer with a single switch-enable (\overline{E}) input. When \overline{E} is low, the switch is enabled and the I port is connected to the Y port. When \overline{E} is high, the switch is disabled and the high-impedance state exists between the I and Y ports. The select (S) input controls the data path of the multiplexer/demultiplexer.

ORDERING INFORMATION

TA	PACKAGE [†]		ORDERABLE PART NUMBER	TOP-SIDE MARKING
0°C to 70°C	QFN – RGY	Tape and reel	TS3L100RGYR	TK100
	COIC D	Tube	TS3L100D	TC21 400
	SOIC – D	Tape and reel	TS3L100DR	TS3L100
	SSOP (QSOP) – DBQ	Tape and reel	TS3L100DBQR	TK100
	TOOOD DW	Tube	TS3L100PW	TI(400
	TSSOP – PW	Tape and reel	TS3L100PWR	TK100
	TVSOP - DGV	Tape and reel	TS3L100DGVR	TK100

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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TS3L100 QUAD SPDT WIDE-BANDWIDTH LAN SWITCH WITH LOW ON-STATE RESISTANCE

SCDS161 - MAY 2004

description/ordering information (continued)

This device can be used to replace mechanical relays in LAN applications. This device has low r_{on} , wide bandwidth, and low differential crosstalk, making it suitable for 10 Base-T, 100 Base-T, and various other LAN applications.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down, \overline{E} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

FUNCTION TABLE

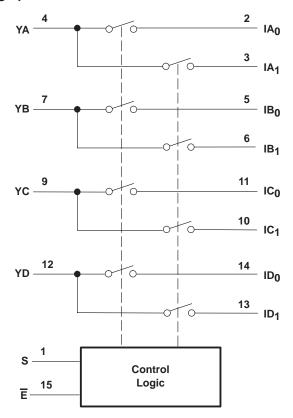
INPUTS		INPUT/OUTPUT	ELINIOTION.
Ē	S	YX	FUNCTION
L	L	IX ₀	$YX = IX_0$
L	Н	IX ₁	$YX = IX_1$
Н	X	Z	Disconnect

PIN DESCRIPTIONS

PIN NAME	DESCRIPTION
IAn–IDn	Data I/Os
S	Select input
Ē	Enable input
YA-YD	Data I/Os



logic diagram (positive logic)



TS3L100 QUAD SPDT WIDE-BANDWIDTH LAN SWITCH WITH LOW ON-STATE RESISTANCE

SCDS161 - MAY 2004

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage range, V _{CC}		–0.5 V to 4.6 V
Control input voltage range, V _{IN} (see Notes 1 a		
Switch I/O voltage range, V _{I/O} (see Notes 1, 2,		
Control input clamp current, I _{IK} (V _{IN} < 0)		
I/O port clamp current, $I_{I/OK}$ ($V_{I/O} < 0$)		–50 mA
ON-state switch current, I _{I/O} (see Note 4)		±128 mA
Continuous current through V _{CC} or GND termin	nals	±100 mA
Package thermal impedance, θ _{JA} (see Note 5):	: D package	73°C/W
	DB package	82°C/W
	DBQ package	90°C/W
	PW package	108°C/W
Storage temperature range, T _{stg}		–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltages are with respect to ground, unless otherwise specified.
 - 2. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
 - 3. V_I and V_O are used to denote specific conditions for V_{I/O}.
 - 4. II and IO are used to denote specific conditions for II/O.
 - 5. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 6)

		MIN	MAX	UNIT
V _{CC}	Supply voltage	3	3.6	V
V_{IH}	High-level control input voltage (\overline{E},S)	2	VCC	V
V _{IL}	Low-level control input voltage ($\overline{\overline{E}}$, S)	0	8.0	V
TA	Operating free-air temperature	0	70	°C

NOTE 6: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



electrical characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted)

PARA	METER		TEST CONDI	TIONS	MIN	TYP [†]	MAX	UNIT
VIK	Ē, S	$V_{CC} = 3 V$,	$I_{IN} = -18 \text{ mA}$				-1.8	V
V _{hys}	Ē, S					150		mV
lіН	Ē, S	$V_{CC} = 3.6 \text{ V},$	VIN = VCC				±1	μΑ
IIL	E, S	$V_{CC} = 3.6 \text{ V},$	$V_{IN} = GND$				±1	μΑ
loz‡		V _{CC} = 3.6 V,	$V_O = 0 \text{ to } 3.6 \text{ V},$ $V_I = 0,$	Switch OFF			±1	μΑ
los§		V _{CC} = 3.6 V,	$V_O = 0 \text{ to } 0.5 V_{CC},$ $V_I = 0,$	Switch ON	50			mA
l _{off}		$V_{CC} = 0$,	$V_0 = 0 \text{ to } 3.6 \text{ V},$	V _I = 0			15	μΑ
ICC		$V_{CC} = 3.6 \text{ V},$	$I_{I/O} = 0$,	Switch ON or OFF		0.1	3	μΑ
∆ICC	E, S	$V_{CC} = 3.6 \text{ V},$	One input at V _{CC} – 0.6 V,	Other inputs at V _{CC} or GND			750	μΑ
ICCD		V _{CC} = 3.6 V,	I and Y ports open,	V _{IN} input switching 50% duty cycle			0.45	mA/ MHz
C _{IN}	Ē, S	f = 1 MHz				3		pF
0	I port	\\. 0	f = 1 MHz,	Cuitab OFF		5		
COFF	Y port	$V_{\parallel} = 0$,	Outputs open,	Switch OFF		10		pF
CON		V _I = 0,	f = 1 MHz, Outputs open,	Switch ON		17		pF
_	$V_{\parallel} = 0 V$	I _O = 48 mA		5	7			
ron		VCC = 3 V	V _I = 2 V,	I _O = 15 mA		10	15	Ω
Δr _{on}		V _I = 3 V,	Switch ON,	I _O = 15 mA		1		Ω

 $V_{\mbox{\scriptsize I}},\,V_{\mbox{\scriptsize O}},\,I_{\mbox{\scriptsize I}},$ and $I_{\mbox{\scriptsize O}}$ refer to I/O pins. $V_{\mbox{\scriptsize IN}}$ refers to the control inputs.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V, R_L = 100 Ω , C_L = 35 pF (unless otherwise noted) (see Figure 4)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	MIN	MAX	UNIT
tON	S	Υ	1	7.5	ns
tOFF	S	Υ	1	3.5	ns

[†] All typical values are at $V_{CC} = 3.3 \text{ V}$ (unless otherwise noted), $T_A = 25^{\circ}\text{C}$.

dynamic characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		TYP	UNIT
X _{TALK} (Diff)	$R_L = 100 \Omega$,	f = 10 MHz, see Figure 8,	$t_{\Gamma} = t_{f} = 2 \text{ ns}$	-55	dB
X _{TALK}	$R_L = 100 \Omega$,	f = 30 MHz, see Figure 6		-68	dB
O _{IRR}	$R_L = 100 \Omega$,	f = 30 MHz, see Figure 7		-42	dB
BW	R_L = 100 $Ω$, see Figu	ure 5		350	MHz

[†] All typical values are at V_{CC} = 3.3 V (unless otherwise noted), T_A = 25°C.

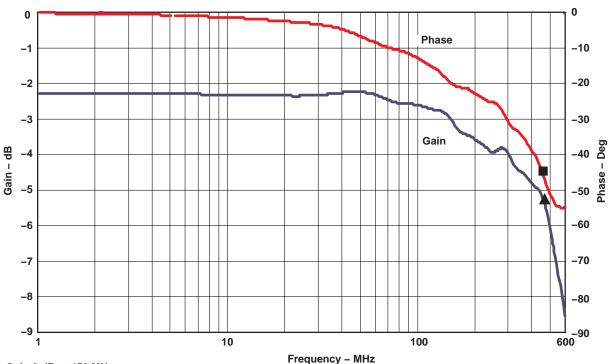


[†] All typical values are at $V_{CC} = 3.3 \text{ V}$ (unless otherwise noted), $T_A = 25^{\circ}C$.

[‡] For I/O ports, the parameter IOZ includes the input leakage current.

[§] The IOS test is applicable to only one ON channel at a time. The duration of this test is less than one second.

OPERATING CHARACTERISTICS

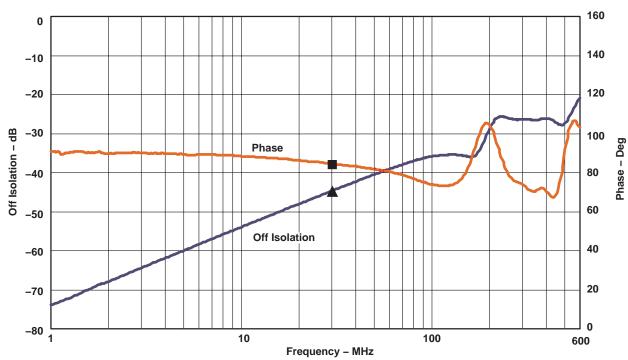


- ▲ Gain 3 dB at 450 MHz
- Phase at 3-dB Frequency, -43 Degrees

Figure 1. Gain/Phase vs Frequency



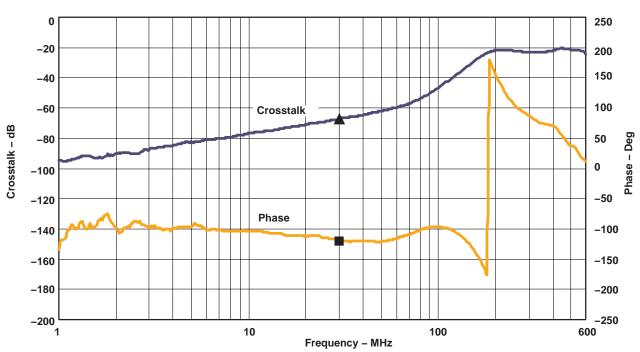
OPERATING CHARACTERISTICS



- ▲ Off Isolation at 30 MHz, -44.6 dB
- Phase at 30 MHz, 84.41 Degrees

Figure 2. Off Isolation vs Frequency

OPERATING CHARACTERISTICS

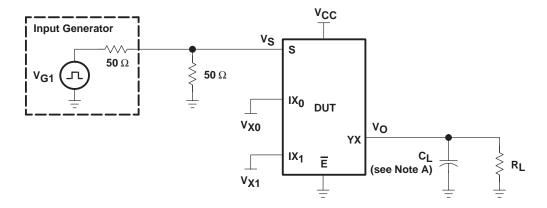


- ▲ Crosstalk at 30 MHz, -67.3 dB
- Phase at 30 MHz, -118.4 Degrees

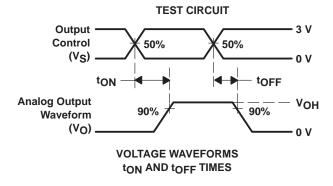
Figure 3. Crosstalk vs Frequency



PARAMETER MEASUREMENT INFORMATION



TEST	VCC	RL	CL	V _{X0}	V _{X1}
ton	3.3 V ± 0.3 V	100 Ω	35 pF	GND	3 V
	3.3 V ± 0.3 V	100 Ω	35 pF	3 V	GND
tOFF	3.3 V ± 0.3 V	100 Ω	35 pF	GND	3 V
	3.3 V ± 0.3 V	100 Ω	35 pF	3 V	GND



NOTES: A. C_L includes probe and jig capacitance.

- B. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_{O} = 50 \Omega$, $t_{f} \leq$ 2.5 ns, $t_{f} \leq$ 2.5 ns.
- C. The outputs are measured one at a time, with one transition per measurement.

Figure 4. Test Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION

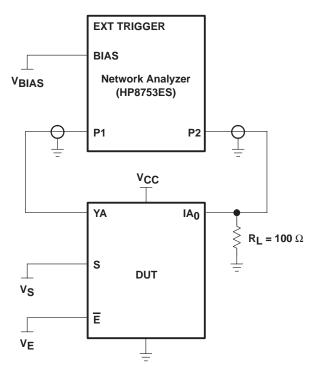


Figure 5. Test Circuit for Frequency Response (BW)

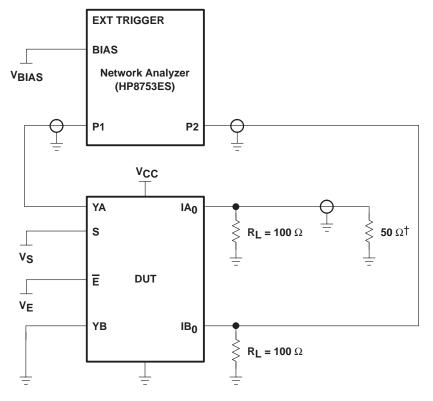
Frequency response is measured at the output of the ON channel. For example, when $V_S = 0$, $V_E = 0$, and YA is the input, the output is measured at IA₀. All unused analog I/O ports are left open.

HP8753ES setup

Average = 4 RBW = 3 kHz V_{BIAS} = 0.35 V ST = 2 s P1 = 0 dBM



PARAMETER MEASUREMENT INFORMATION



 \dagger A 50- $\!\Omega$ termination resistor is needed for the network analyzer.

Figure 6. Test Circuit for Crosstalk (X_{TALK})

Crosstalk is measured at the output of the nonadjacent ON channel. For example, when $V_S=0$, $V_E=0$, and YA is the input, the output is measured at IB_0 . All unused analog input (Y) ports are connected to GND and output (I) ports are connected to GND through $50-\Omega$ pulldown resistors.

HP8753ES setup

Average = 4

RBW = 3 kHz

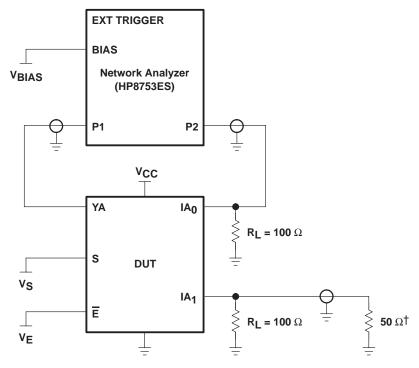
 $V_{BIAS} = 0.35 V$

ST = 2 s

P1 = 0 dBM



PARAMETER MEASUREMENT INFORMATION



 $[\]dagger$ A 50-Ω termination resistor is needed for the network analyzer.

Figure 7. Test Circuit for Off Isolation (OIRR)

OFF isolation is measured at the output of the OFF channel. For example, when $V_S = V_{CC}$, $V_E = 0$, and YA is the input, the output is measured at IA₀. All unused analog input (Y) ports are left open and output (I) ports are connected to GND through 50- Ω pulldown resistors.

HP8753ES setup

Average = 4 RBW = 3 kHz $V_{BIAS} = 0.35 V$ ST = 2 s P1 = 0 dBM



PARAMETER MEASUREMENT INFORMATION

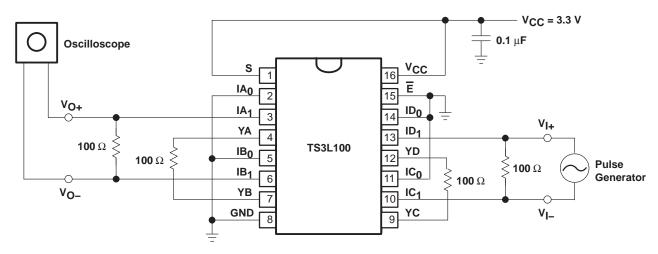


Figure 8. Differential Crosstalk Measurement

Differential crosstalk is a measure of coupling noise between a transmit and receive pair in the LAN application. Differential crosstalk depends on the edge rate, frequency, and load. This is calculated from the equation, $X_{TALK}(Diff)$ db = 20 log $V_{O}(Diff)/V_{I}(Diff)$, where $V_{O}(Diff)$ is the differential output voltage and $V_{I}(Diff)$ is the differential input voltage.

DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE

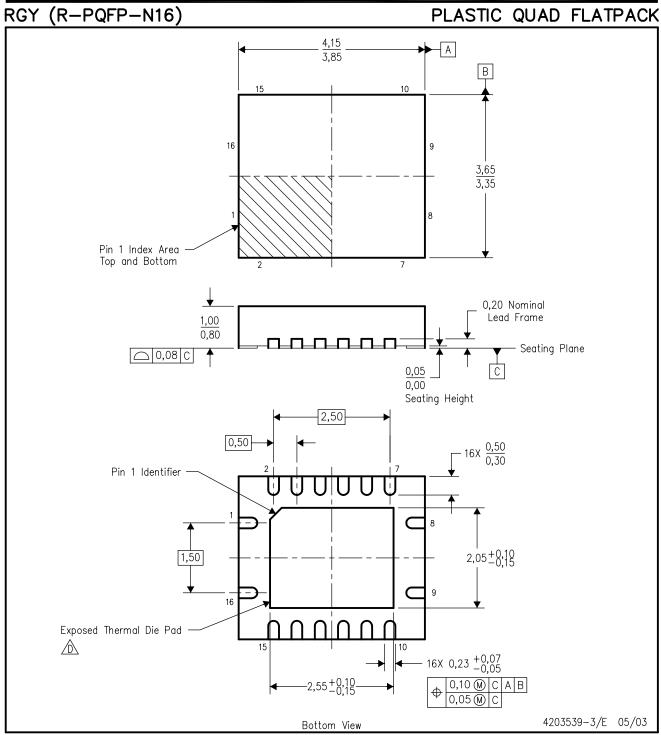


NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194



- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. QFN (Quad Flatpack No-Lead) package configuration.
 - The package thermal performance may be enhanced by bonding the thermal die pad to an external thermal plane.

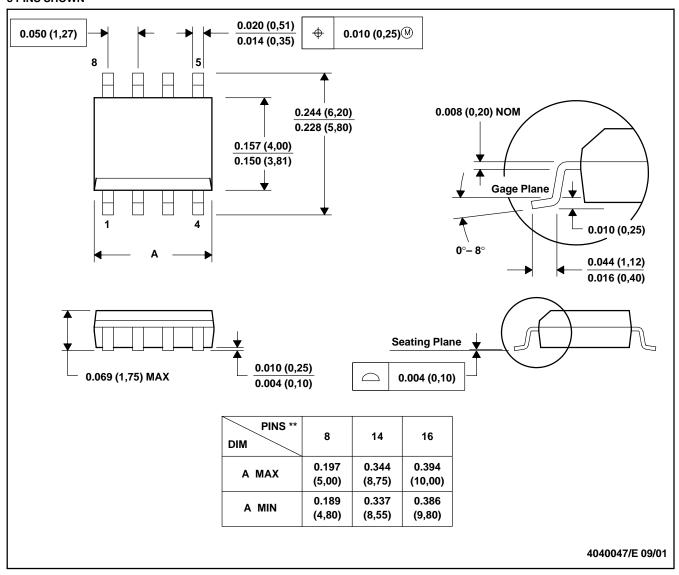
 This pad is electrically and thermally connected to the backside of the die and possibly selected ground leads.
 - E. Package complies to JEDEC MO-241 variation BB.



D (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

8 PINS SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

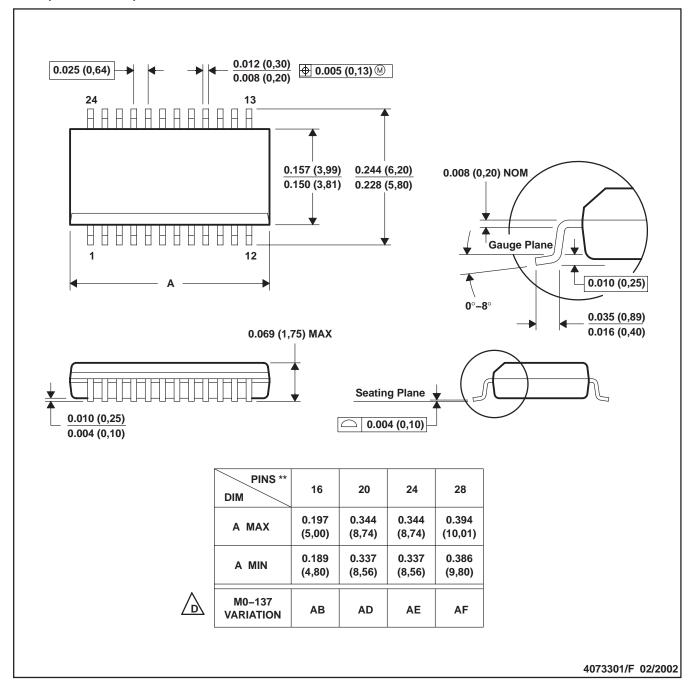
B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-012

DBQ (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MO-137.



PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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